

090107082027

ANNA UNIVERSITY OF TECHNOLOGY, COIMBATORE  
B.E. / B.TECH. DEGREE EXAMINATIONS : NOV / DEC 2010

REGULATIONS : 2008

THIRD SEMESTER

080290011 - ELECTRONIC CIRCUITS I  
(COMMON TO ECE / MEDICAL ELECTRONICS)

Time : 3 Hours

Max.Marks : 100

PART - A

(20 x 2 = 40 MARKS)

ANSWER ALL QUESTIONS

1. What do you mean by faithful amplification?
2. What are the three operating region of BJT?
3. What are temperature dependent parameters in transistor?
4. What is thermal runaway?
5. Give four advantage of h – parameter method for analyzing transistor amplifier over other types.
6. Consider CE amplifier with fixed bias. If  $\beta = 80$ ,  $R_B = 390 \text{ K}\Omega$ ,  $R_C = 1.5 \text{ K}\Omega$  &  $V_{CC} = 30 \text{ V}$ . Find the coordinates of Q-point.
7. What is the role of coupling network in multistage amplifier?
8. State Miller's Theorem.
9. Draw the High frequency model of FET.
10. How the constant current circuit is used to improve the CMRR?
11. Draw the high frequency equivalent circuit for BJT amplifier.
12. Give the main reason for the drop in gain at the low frequency region and high frequency region.

13. Compare the efficiency of class A, and class B amplifiers .
14. How are amplifiers classified based on the biasing condition?
15. How the conversation efficiency occurs?
16. How the crossover distortion occurs.
17. What is meant by ripple factor?
18. A full wave rectifier delivers 50 W to a load of 200  $\Omega$ . If the ripple factor is 1%. Calculate the A.C ripple voltage across the load.
19. Define line and load regulation.
20. Give any four advantages of SMPS.

PART - B

(5 x 12 = 60 MARKS)

ANSWER ANY FIVE QUESTIONS

21a. In the transistor amplifier shown in figure 1,  $R_C = 10 \text{ K}\Omega$ ,  $R_B = 1 \text{ K}\Omega$ ,  $R_L = 24 \text{ K}\Omega$ , and  $V_{CC} = 24 \text{ V}$ .

Draw the DC,AC load line and determine the optimum operating point. (6)

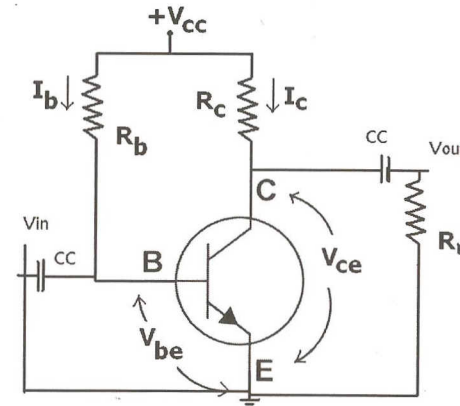


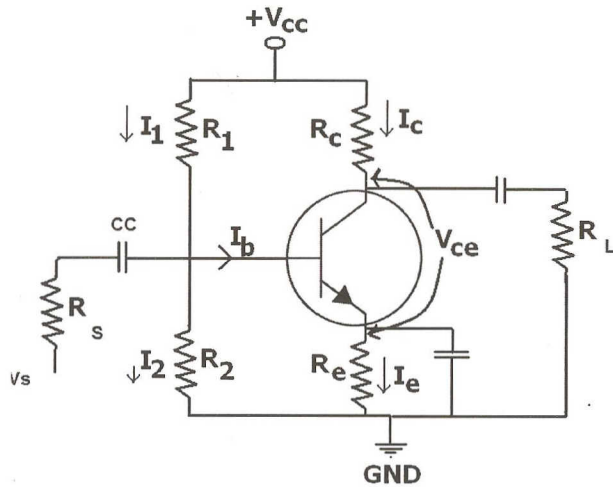
Figure 1

b. Discuss the bias compensation in diode.

(6)

22. Draw a voltage divider bias circuit and derive an expression for its stability factor. Give the advantage of voltage divider bias over other types of biasing.

23. Consider a single stage CE amplifier with  $R_s=1\text{ K}\Omega$ ,  $R_1=50\text{ K}\Omega$ ,  $R_2=R_E=R_C=2\text{ K}\Omega$ ,  $R_L=2\text{ K}\Omega$ ,  $h_{fe}=50$ ,  $h_{ie}=1.1\text{ K}\Omega$ ,  $h_{oe}=25\text{ }\mu\text{A/V}$  &  $h_{re}=2.5 \times 10^{-4}$ . Find  $A_i$ ,  $R_i$ ,  $A_v$ ,  $A_{v_s}$ ,  $A_{i_s}$  &  $R_o$ . Use approximate analysis if permissible.



24. Explain the function of differential amplifier with neat circuit. Derive its  $A_d$ ,  $A_c$  and CMRR.

25. Discuss the effect of emitter by pass capacitor on low frequency response of BJT amplifier.

26. a. Draw the circuit diagram of a push pull amplifier and explain its working.

(6)

b. Derive the equation for efficiency of a class B amplifier.

(6)

27. Write short notes on :

i) Harmonic distortion

ii) Frequency distortion

iii) Phase distortion

28. Explain the working principle of full wave rectifier circuit with  $\pi$  filter. Derive its ripple factor.

\*\*\*\*\*THE END\*\*\*\*\*